

DRV5053-Q1 汽车类 模拟双极霍尔效应传感器

1 特性

- 线性输出霍尔传感器
- 符合汽车应用要求的 AEC-Q100 标准
 - 1 级: $T_A = -40$ 至 125°C (Q, 请见图 17)
 - 0 级: $T_A = -40$ 至 150°C (E, 请见图 17)
- 出色的温度稳定性
 - 温度范围内的灵敏度为 $\pm 10\%$
- 高灵敏度选项:
 - -11mV/mT (OA, 请见图 17)
 - -23mV/mT (PA)
 - -45mV/mT (RA)
 - -90mV/mT (VA)
 - $+23\text{mV/mT}$ (CA)
 - $+45\text{mV/mT}$ (EA)
- 支持宽电压范围
 - 2.7V 至 38V
 - 无需外部稳压器
- 放大的输出级
 - 2.3mA 灌电流, $300\mu\text{A}$ 拉电流
- 输出电压: 0.2V 至 1.8V
 - $B = 0\text{mT}$, $\text{OUT} = 1\text{V}$
- 快速上电: $35\mu\text{s}$
- 小型封装尺寸
 - 表面贴装 3 引脚小外形尺寸晶体管 (SOT)-23 (DBZ)
 - $2.92\text{mm} \times 2.37\text{mm}$
 - 插入式 3 引脚系统级封装 (SIP) (LPG)
 - $4.00\text{mm} \times 3.15\text{mm}$
- 保护特性
 - 反向电源保护 (高达 -22V)
 - 支持高达 40V 抛负载
 - 输出短路保护
 - 输出电流限制
 - 电池输出短路保护

2 应用

- 流量计
- 对接调整
- 振动校正
- 减震器控制

3 说明

DRV5053-Q1 器件是一款斩波稳定霍尔 IC, 能够在整个温度范围内提供具有出色灵敏度稳定性和集成保护特性的磁场感测解决方案。

0V 至 2V 模拟输出可对施加的磁感应强度做出线性响应, 并且能够辨别磁场方向的极性。反向极性保护高达 -22V 的宽工作电压范围 (2.7V 至 38V) 使得此器件适用于广泛的汽车和消费类应用。

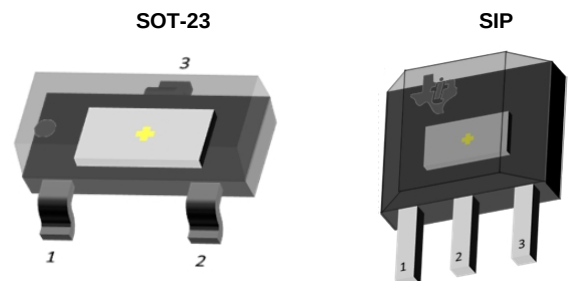
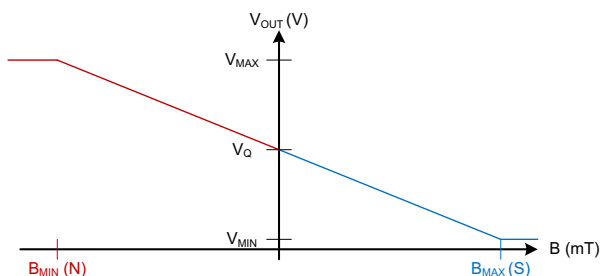
针对反向电源情况、负载突降和输出短路或过流提供内部保护功能。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
DRV5053-Q1	SOT-23 (3)	$2.92\text{mm} \times 2.37\text{mm}$
	SIP (3)	$4.00\text{mm} \times 3.15\text{mm}$

(1) 要了解所有可用封装, 请见数据表末尾的可订购产品附录。

4 输出状态



目录

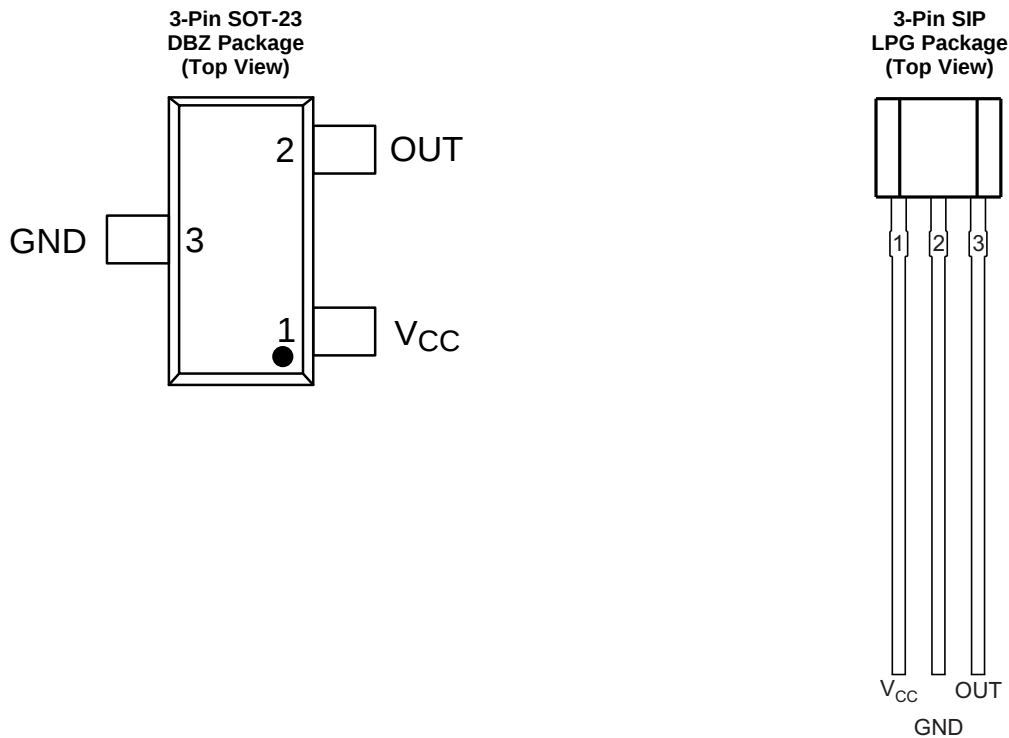
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5 修订历史记录

日期	修订版本	注释
2014年12月	*	最初发布。

6 Pin Configuration and Functions

For additional configuration information, see [器件标记](#) and [机械封装和可订购信息](#).



Pin Functions

PIN			TYPE	DESCRIPTION
NAME	DBZ	LPG		
GND	3	2	GND	Ground pin
V _{CC}	1	1	Power	2.7 to 38 V power supply. Bypass this pin to the GND pin with a 0.01-μF (minimum) ceramic capacitor rated for V _{CC} .
OUT	2	3	Output	Hall sensor analog output. 1 V output corresponds to B = 0 mT

7 Specifications

7.1 Absolute Maximum Ratings

 over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Power supply voltage	V _{CC}	–22 ⁽²⁾	40	V
	Voltage ramp rate (V _{CC}), V _{CC} < 5 V	Unlimited		V/μs
	Voltage ramp rate (V _{CC}), V _{CC} > 5 V	0	2	
Output pin voltage	OUT	–0.5	2.5	V
Output pin reverse current during reverse supply condition	OUT	0	–20	mA
Operating junction temperature, T _J	Q, see Figure 17	–40	150 ⁽³⁾	°C
	E, see Figure 17	–40	175 ⁽⁴⁾	
T _{stg}	Storage temperature range	–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Ensured by design. Only tested to –20 V.
- (3) Tested in production to T_A = 125°C.
- (4) Tested in production to T_A = 150°C.

7.2 ESD Ratings

		VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	±2500
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	±500

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
V _{CC}	Power supply voltage	2.7	38	V
V _{OUT}	Output pin voltage (OUT)	0	2	V
I _{SOURCE}	Output pin current source (OUT)	0	300	μA
I _{SINK}	Output pin current sink (OUT)	0	2.3	mA
T _A	Operating ambient temperature	Q, see Figure 17	–40	125
		E, see Figure 17	–40	150

7.4 Thermal Information

THERMAL METRIC ⁽¹⁾		DRV5053-Q1		UNIT
		DBZ	LPG	
		3 PINS	3 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	333.2	180	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	99.9	98.6	
R _{θJB}	Junction-to-board thermal resistance	66.9	154.9	
Ψ _{JT}	Junction-to-top characterization parameter	4.9	40	
Ψ _{JB}	Junction-to-board characterization parameter	65.2	154.9	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

7.5 Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLIES (V_{CC})						
V _{CC}	V _{CC} operating voltage		2.7		38	V
I _{CC}	Operating supply current	V _{CC} = 2.7 to 38 V, T _A = 25°C		2.7		mA
		V _{CC} = 2.7 to 38 V, T _A = T _{A, MAX} ⁽¹⁾		3	3.6	
t _{on}	Power-on time			35	50	μs
PROTECTION CIRCUITS						
V _{CCR}	Reverse supply voltage		–22			V
I _{OCPSOURCE}	Overcurrent protection level	Sourcing current		300		μA
I _{OCPSINK}	Overcurrent protection level	Sinking current		2.3		mA

(1) T_{A, MAX} is 125°C for Q Grade 1 devices and 150°C for E Grade 0 devices (see [Figure 17](#))

7.6 Switching Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
ANALOG OUTPUT (OUT)						
t _d	Output delay time	T _A = 25°C		13	25	μs

7.7 Magnetic Characteristics

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT ⁽¹⁾
V _Q	Quiescent output	B = 0 mT	0.9	1.02	1.15	V
f _{BW}	Bandwidth ⁽²⁾		20			kHz
B _N	Input-referred noise ⁽³⁾	C _{OUT} = 50 pF	0.40	0.58	0.79	mT _{pp}
Le	Linearity ⁽⁴⁾	–B _{SAT} < B < B _{SAT}		1%		
V _{OUT MIN}	Output saturation voltage (min)	B < –B _{SAT}			0.2	V
V _{OUT MAX}	Output saturation voltage (max)	B > B _{SAT}	1.8			V
DRV5053OA: –11 mV/mT						
S	Sensitivity	V _{CC} = 3.3 V	–17.5	–11	–5	mV/mT
V _N	Output-referred noise ⁽³⁾	V _{CC} = 3.3 V; R _{OUT} = 10 kΩ; C _{OUT} = 50 pF		6		mV _{pp}
B _{SAT}	Input saturation field	V _{CC} = 3.3 V		73		mT
DRV5053PA: –23 mV/mT						
S	Sensitivity	V _{CC} = 3.3 V	–35	–23	–10	mV/mT
V _N	Output-referred noise ⁽³⁾	V _{CC} = 3.3 V; R _{OUT} = 10 kΩ; C _{OUT} = 50 pF		13		mV _{pp}
B _{SAT}	Input saturation field	V _{CC} = 3.3 V		35		mT

(1) 1 mT = 10 Gauss

(2) Bandwidth describes the fastest changing magnetic field that can be detected and translated to the output.

(3) Not tested in production; limits are based on characterization data.

(4) Linearity describes the change in sensitivity across the B-range. The sensitivity near B_{SAT} is typically within 1% of the sensitivity near B = 0.

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Magnetic Characteristics (continued)

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT ⁽¹⁾
DRV5053RA: –45 mV/mT						
S	Sensitivity	$V_{CC} = 3.3\text{ V}$	–70	–45	–20	mV/mT
V_N	Output-referred noise ⁽³⁾	$V_{CC} = 3.3\text{ V}; R_{OUT} = 10\text{ k}\Omega;$ $C_{OUT} = 50\text{ pF}$		26		mV _{pp}
B_{SAT}	Input saturation field	$V_{CC} = 3.3\text{ V}$		18		mT
DRV5053VA: –90 mV/mT						
S	Sensitivity	$V_{CC} = 3.3\text{ V}$	–140	–90	–45	mV/mT
V_N	Output-referred noise ⁽³⁾	$V_{CC} = 3.3\text{ V}; R_{OUT} = 10\text{ k}\Omega;$ $C_{OUT} = 50\text{ pF}$		52		mV _{pp}
B_{SAT}	Input saturation field	$V_{CC} = 3.3\text{ V}$		9		mT
DRV5053CA: 23 mV/mT						
S	Sensitivity	$V_{CC} = 3.3\text{ V}$	10	23	35	mV/mT
V_N	Output-referred noise ⁽³⁾	$V_{CC} = 3.3\text{ V}; R_{OUT} = 10\text{ k}\Omega;$ $C_{OUT} = 50\text{ pF}$		13		mV _{pp}
B_{SAT}	Input saturation field	$V_{CC} = 3.3\text{ V}$		35		mT
DRV5053EA: 45 mV/mT						
S	Sensitivity	$V_{CC} = 3.3\text{ V}$	20	45	70	mV/mT
V_N	Output-referred noise ⁽³⁾	$V_{CC} = 3.3\text{ V}; R_{OUT} = 10\text{ k}\Omega;$ $C_{OUT} = 50\text{ pF}$		26		mV _{pp}
B_{SAT}	Input saturation field	$V_{CC} = 3.3\text{ V}$		18		mT

7.8 Typical Characteristics

$T_A > 125^\circ\text{C}$ data is valid for Grade 0 devices only (E, see [Figure 17](#))

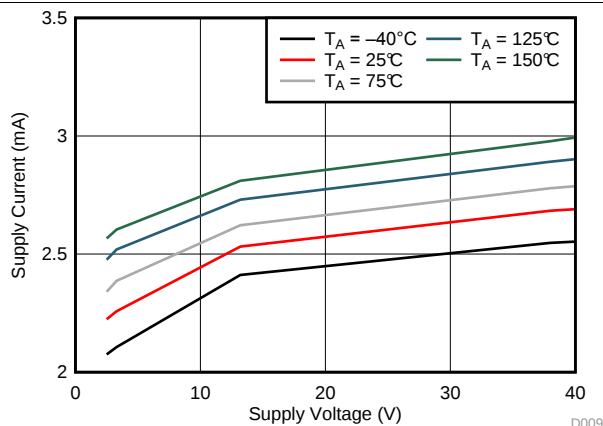


Figure 1. I_{CC} vs V_{CC}

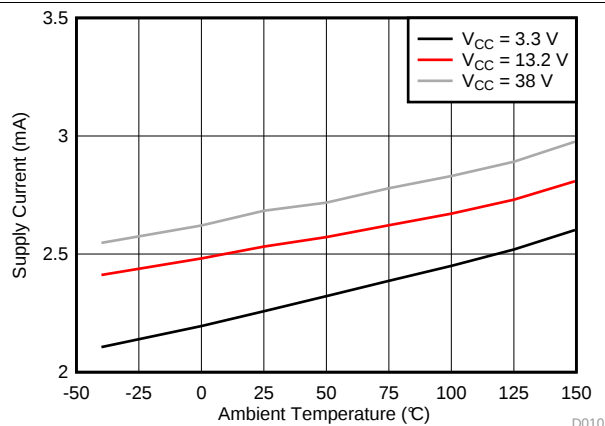


Figure 2. I_{CC} vs Temperature

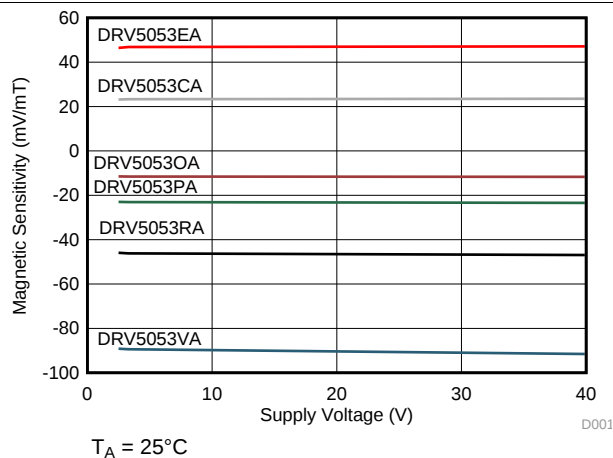


Figure 3. Sensitivity vs V_{CC}

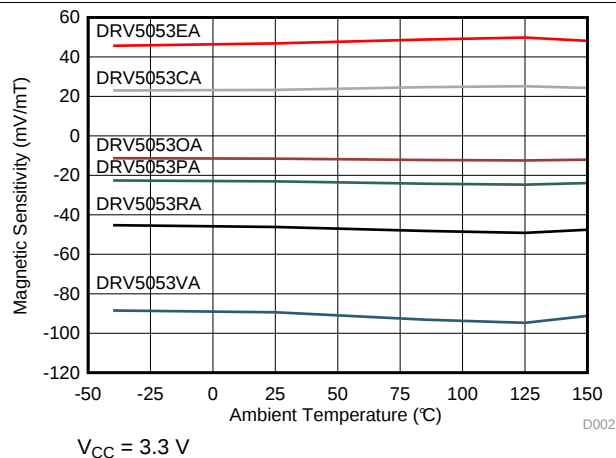


Figure 4. Sensitivity vs Temperature

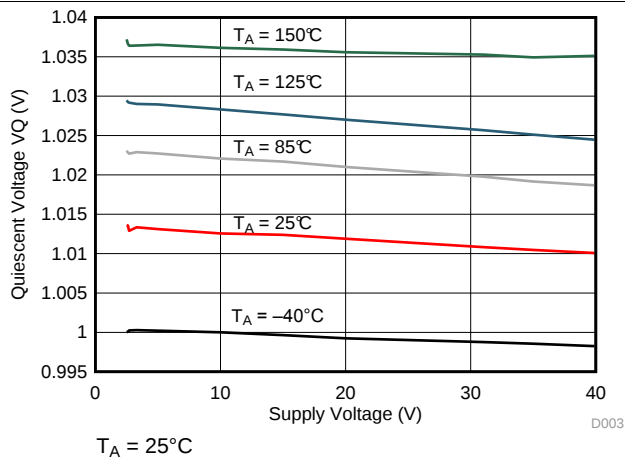


Figure 5. DRV5053-Q1AD, V_Q vs V_{CC}

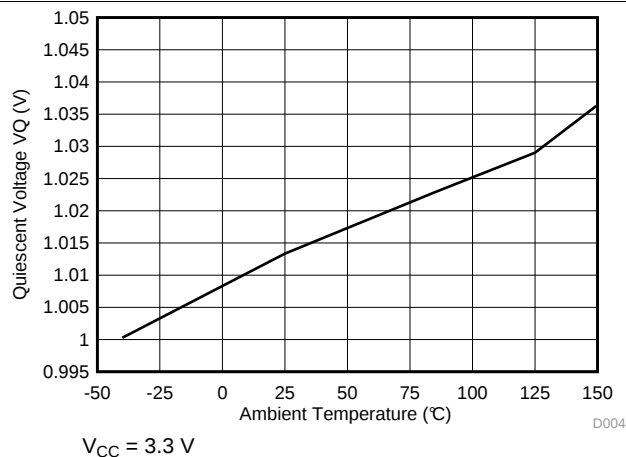


Figure 6. DRV5053-Q1AD, B_N vs Temperature

8 Detailed Description

8.1 Overview

The DRV5053-Q1 device is a chopper-stabilized hall sensor with an analog output for magnetic sensing applications. The DRV5053-Q1 device can be powered with a supply voltage between 2.7 and 38 V, and will survive -22 V reverse battery conditions continuously. Note that the DRV5053-Q1 device will not be operating when approximately -22 to 2.4 V is applied to V_{CC} (with respect to GND). In addition, the device can withstand supply voltages up to 40 V for transient durations.

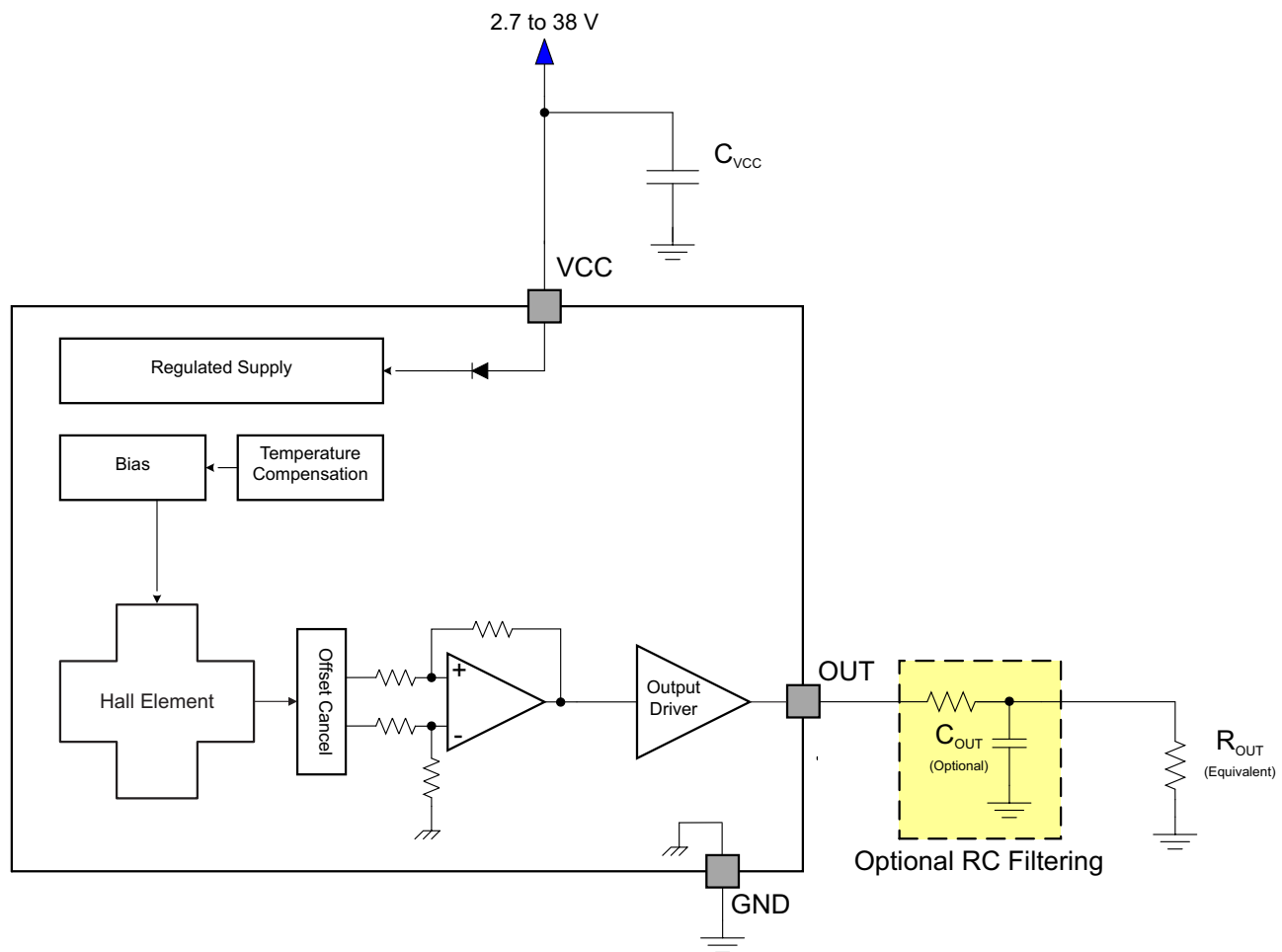
The output voltage is dependent on the magnetic field perpendicular to the package. The absence of a magnetic field will result in $OUT = 1$ V. A magnetic field will cause the output voltage to change linearly with the magnetic field.

The field polarity is defined as follows: a **south pole** near the marked side of the package is a positive magnetic field. A **north pole** near the marked side of the package is a negative magnetic field.

For devices with a negative sensitivity (that is, DRV5053-Q1RA: -40 mV/mT), a **south pole** will cause the output voltage to drop below 1 V, and a north pole will cause the output to rise above 1 V.

For devices with a positive sensitivity (that is, DRV5053-Q1EA: $+40$ mV/mT), a **south pole** will cause the output voltage to rise above 1 V, and a north pole will cause the output to drop below 1 V.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Field Direction Definition

A positive magnetic field is defined as a **south pole** near the marked side of the package as shown in [Figure 7](#).

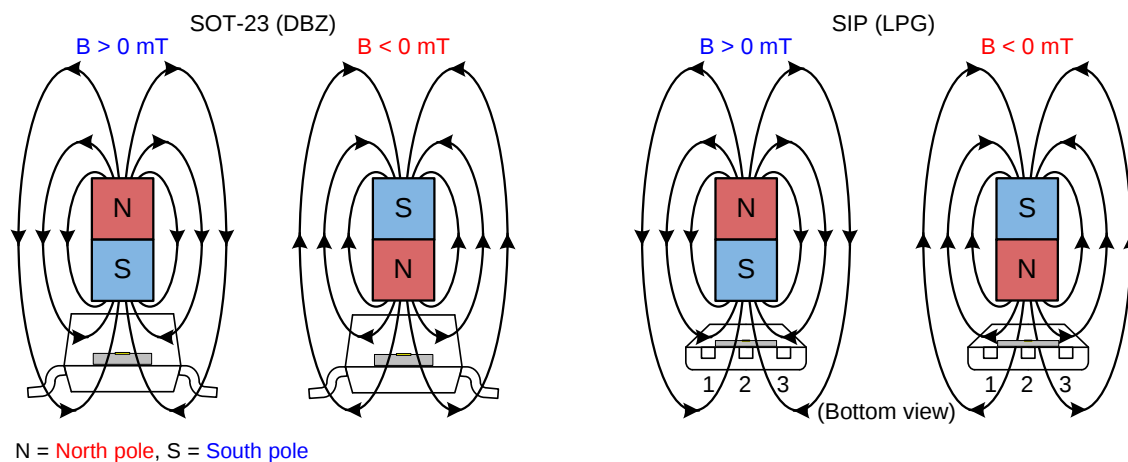


Figure 7. Field Direction Definition

8.3.2 Device Output

The DRV5053-Q1 device output is defined below for negative sensitivity (that is, -45 mV/mT , RA) and positive sensitivity (that is, $+45 \text{ mV/mT}$, EA):

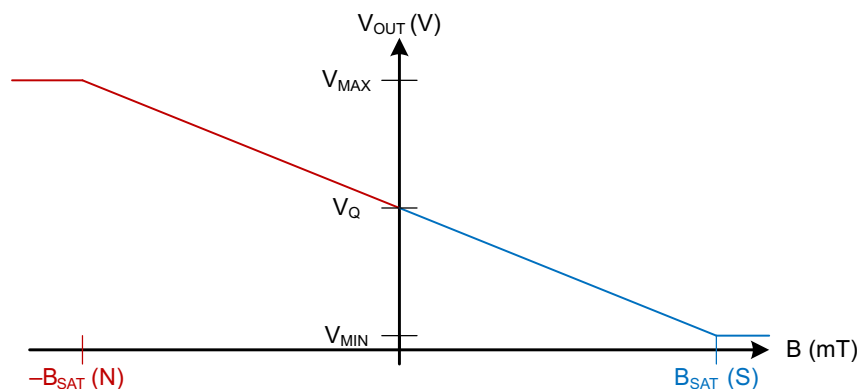


Figure 8. DRV5053-Q1 – Negative Sensitivity

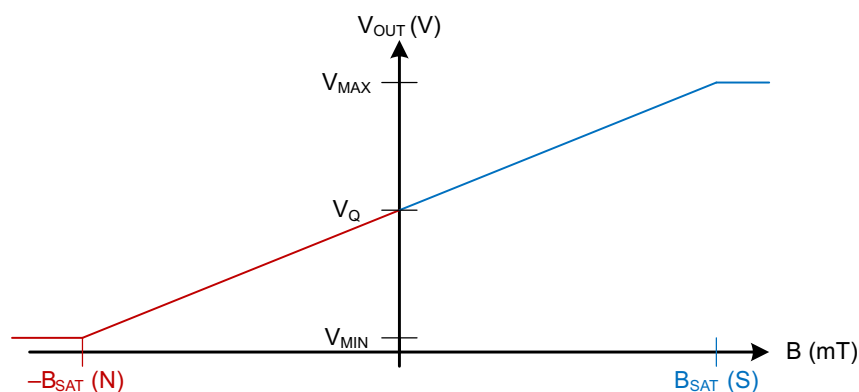


Figure 9. DRV5053-Q1 – Positive Sensitivity

Feature Description (continued)

8.3.3 Power-On Time

After applying V_{CC} to the DRV5053-Q1 device, t_{ON} must elapse before OUT is valid. Figure 10 shows Case 1 and Figure 11 shows case 2; the output is defined assuming a negative sensitivity device and a constant magnetic field $-B_{SAT} < B < B_{SAT}$.

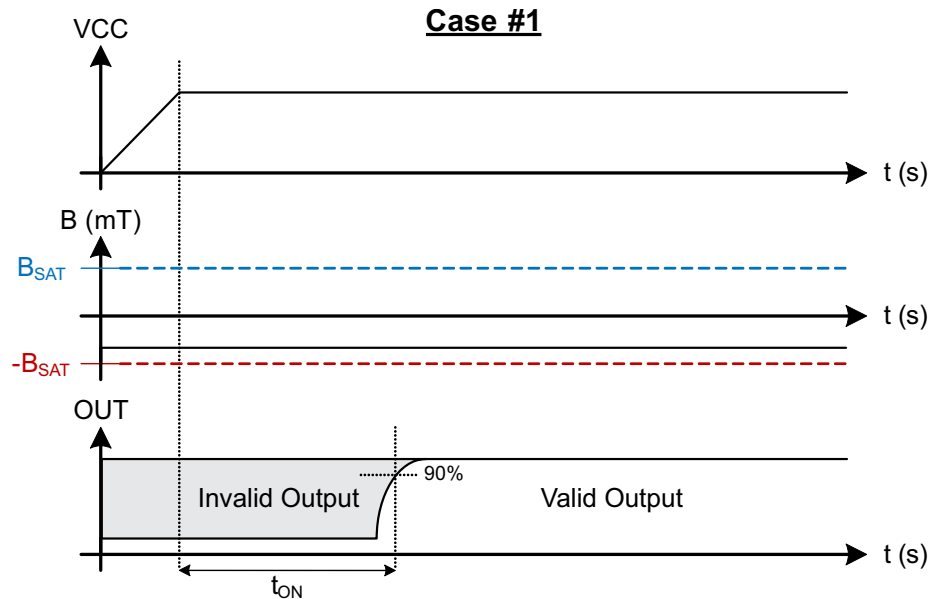


Figure 10. Case 1: Power On When $B < 0$, North

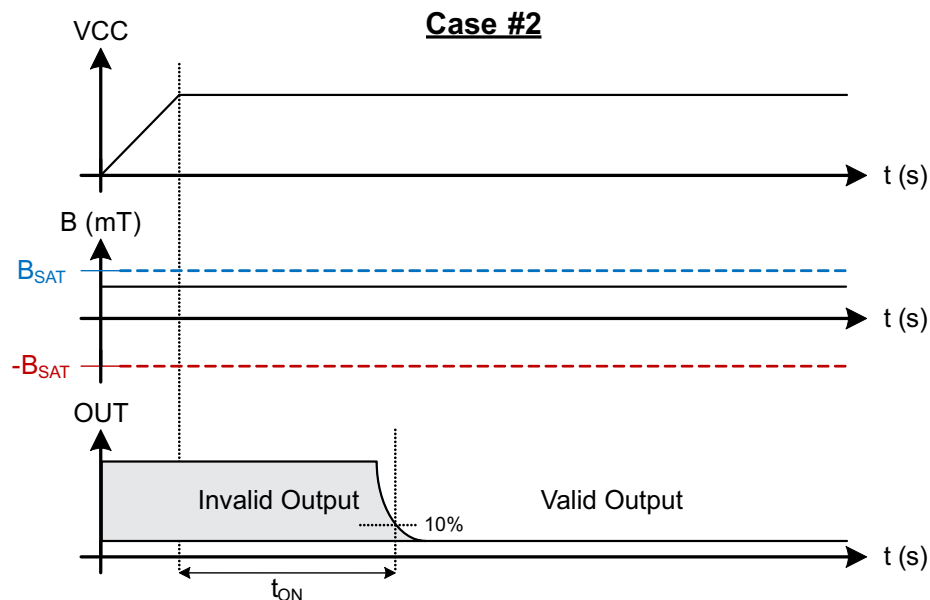


Figure 11. Case 2: Power On When $B > 0$, South

Feature Description (continued)

8.3.4 Output Stage

The DRV5053-Q1 output stage is capable of up to 300 μ A of current source or 2.3 mA sink.

For proper operation, ensure that equivalent output load $R_{OUT} > 10\text{ k}\Omega$. In addition, ensure that the load capacitance $C_{OUT} < 10\text{ nF}$.

8.3.5 Protection Circuits

An analog current limit circuit limits the current through the output driver. The driver current will be clamped to I_{OCP} .

8.3.5.1 Overcurrent Protection (OCP)

An analog current-limit circuit limits the current through the FET. The driver current is clamped to I_{OCP} . During this clamping, the $r_{DS(on)}$ of the output FET is increased from the nominal value.

8.3.5.2 Load Dump Protection

The DRV5053-Q1 device operates at DC V_{CC} conditions up to 38 V nominally, and can additionally withstand $V_{CC} = 40\text{ V}$. No current-limiting series resistor is required for this protection.

8.3.5.3 Reverse Supply Protection

The DRV5053-Q1 device is protected in the event that the V_{CC} pin and the GND pin are reversed (up to -22 V).

NOTE

In a reverse supply condition, the OUT pin reverse-current must not exceed the ratings specified in the [Absolute Maximum Ratings](#).

Table 1.

FAULT	CONDITION	DEVICE	DESCRIPTION	RECOVERY
FET overload (OCP)	$I_{SINK} \geq I_{OCP}$	Operating	Output current is clamped to I_{OCP}	$I_O < I_{OCP}$
Load Dump	$38\text{ V} < V_{CC} < 40\text{ V}$	Operating	Device will operate for a transient duration	$V_{CC} \leq 38\text{ V}$
Reverse Supply	$-22\text{ V} < V_{CC} < 0\text{ V}$	Disabled	Device will survive this condition	$V_{CC} \geq 2.7\text{ V}$

8.4 Device Functional Modes

The DRV5053-Q1 device is active only when V_{CC} is between 2.7 and 38 V.

When a reverse supply condition exists, the device is inactive.

9 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The DRV5053-Q1 device is used in magnetic-field sensing applications.

9.2 Typical Applications

9.2.1 Typical Application With No Filter

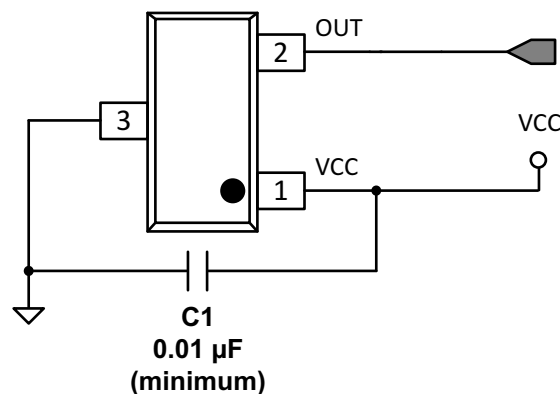


Figure 12. Typical Application Schematic – No Filter

9.2.1.1 Design Requirements

For this design example, use the parameters listed in [Table 2](#) as the input parameters.

Table 2. Design Parameters

DESIGN PARAMETER	REFERENCE	EXAMPLE VALUE
System bandwidth	f_{BW}	15 kHz

9.2.1.2 Detailed Design Procedure

The DRV5053-Q1 has internal filtering that limits the bandwidth to at least 20 kHz. For this application no external components are required other than the C1 bypass capacitor, which is 0.01 μ F minimum. If the analog output OUT is tied to a microcontroller ADC input, the equivalent load must be $R > 10$ k Ω and $C < 10$ nF.

Table 3. External Components

COMPONENT	PIN 1	PIN 2	RECOMMENDED
C1	V _{CC}	GND	A 0.01- μ F (minimum) ceramic capacitor rated for V _{CC}

9.2.1.3 Application Curve

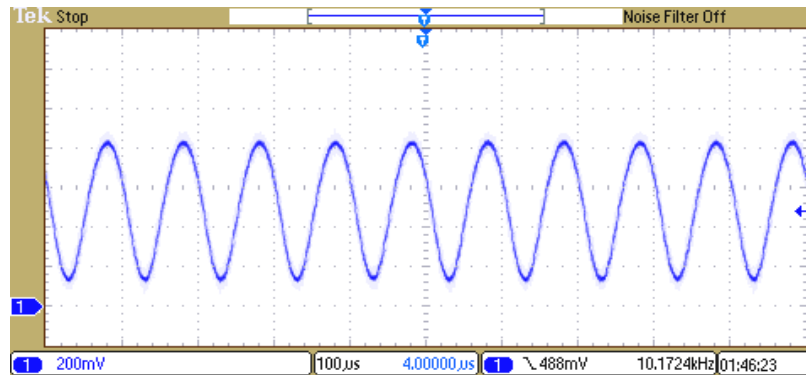


Figure 13. 10-kHz Switching Magnetic Field

9.2.2 Filtered Typical Application

For lower noise on the analog output OUT, additional RC filtering can be added to further reduce the bandwidth.

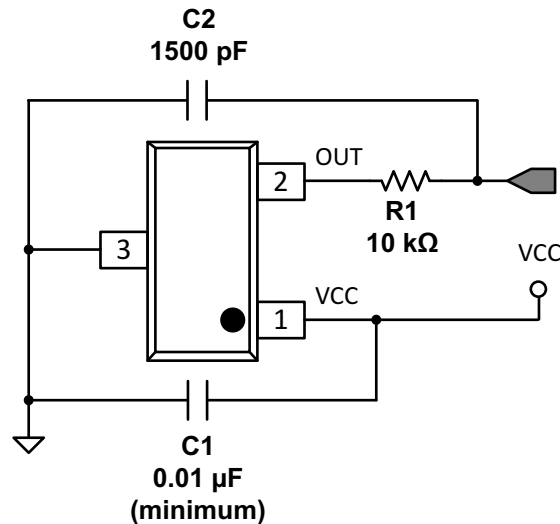


Figure 14. Filtered Typical Application Schematic

9.2.2.1 Design Requirements

For this design example, use the parameters listed in Table 4 as the input parameters.

Table 4. Design Parameters

DESIGN PARAMETER	REFERENCE	EXAMPLE VALUE
System bandwidth	f_{BW}	5 kHz

9.2.2.2 Detailed Design Procedure

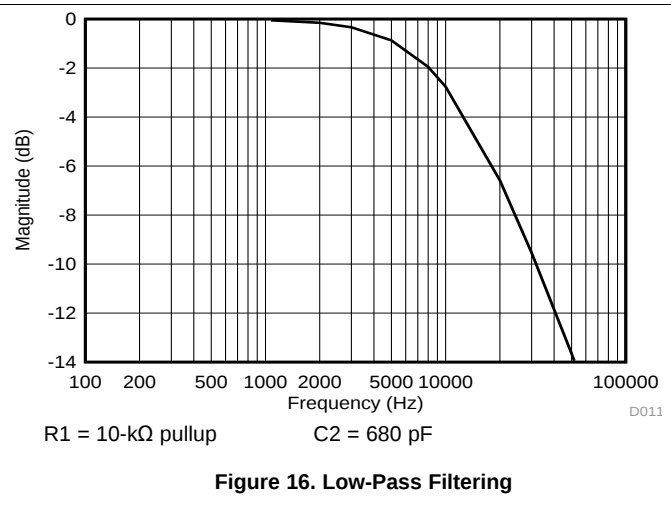
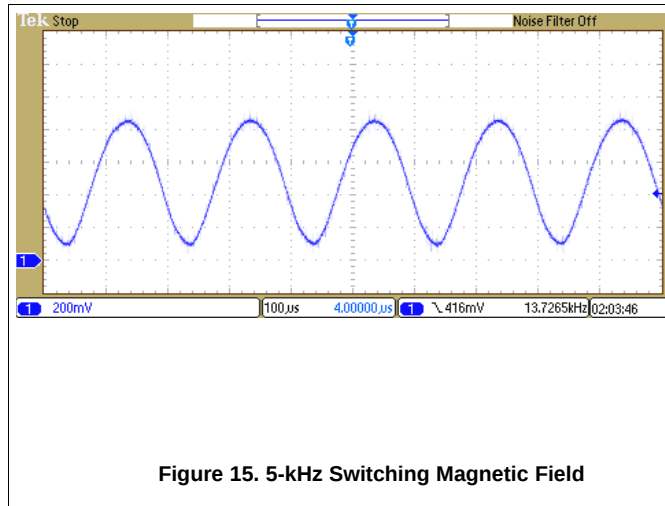
In this example we will add an external RC filter in order to reduce the output bandwidth.

In order to preserve the signal at the frequencies of interest, we will conservatively select a low-pass filter bandwidth (–3-dB point) at twice the system bandwidth (10 kHz).

$$10 \text{ kHz} < \frac{1}{2\pi \times R_1 \times C_2} \quad (1)$$

If we guess $R_1 = 10 \text{ k}\Omega$, then $C_2 < 1590 \text{ pF}$. So we select $C_2 = 1500 \text{ pF}$.

9.2.2.3 Application Curves



10 Power Supply Recommendations

The DRV5053-Q1 device is designed to operate from an input voltage supply (VM) range between 2.7 and 38 V. A 0.01-µF (minimum) ceramic capacitor rated for V_{CC} must be placed as close to the DRV5053-Q1 device as possible.

11 器件和文档支持

11.1 器件支持

11.1.1 器件命名规则

图 17 显示了读取 DRV5053-Q1 器件完整器件名称的图例。

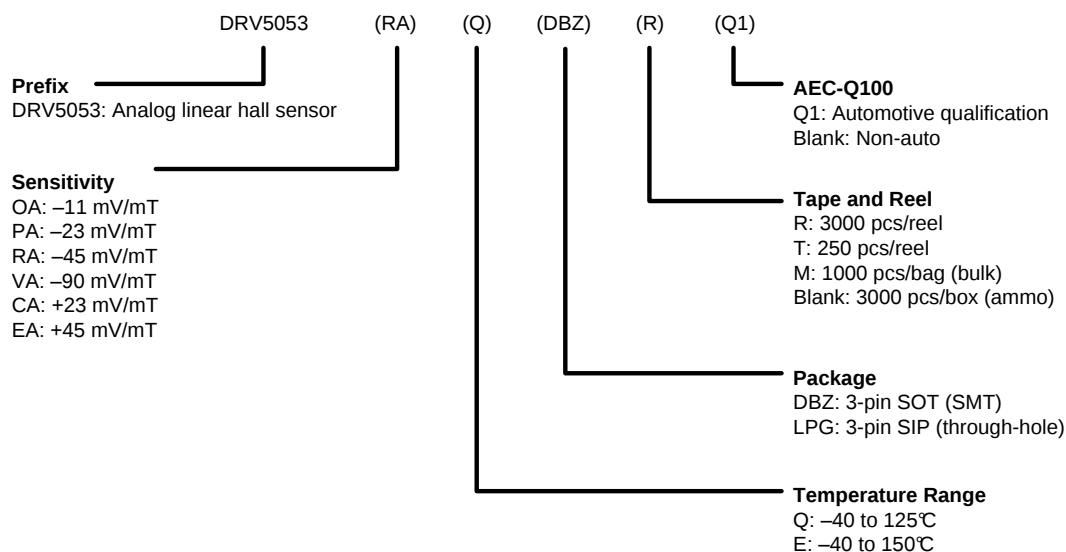


图 17. 器件命名规则

11.1.2 器件标记

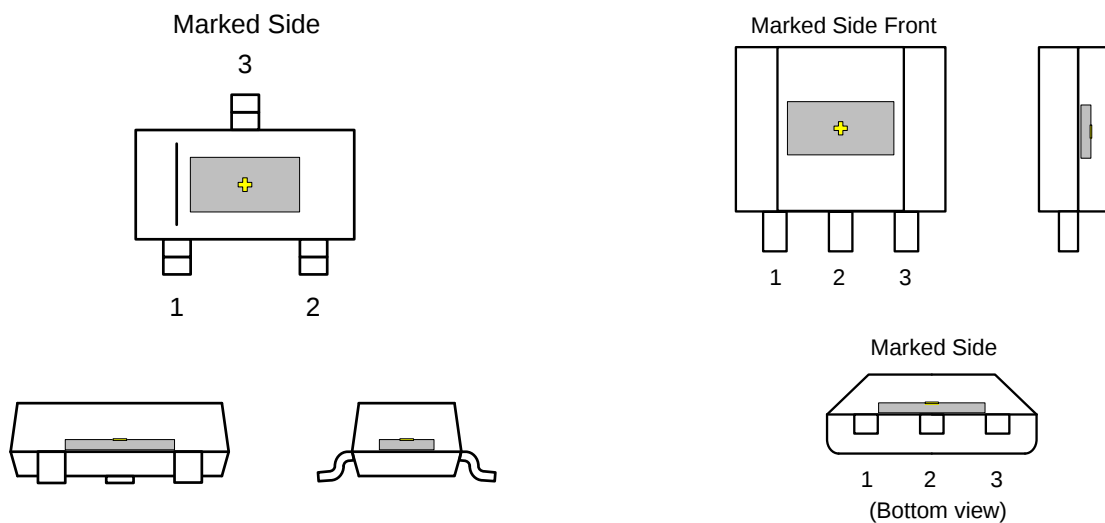


图 18. SOT-23 (DBZ) 封装

图 19. SIP (LPG) 封装

✚ 表示霍尔效应传感器（未按比例显示）。霍尔元件置于封装中央位置，容差为 $\pm 100\mu\text{m}$ 。在 DBZ 封装中，霍尔元件与封装底部的距离为 $0.7\text{mm} \pm 50\mu\text{m}$ ；在 LPG 封装中，霍尔元件与封装底部的距离为 $0.987\text{mm} \pm 50\mu\text{m}$ 。

11.2 商标

All trademarks are the property of their respective owners.

11.3 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.4 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

12 机械封装和可订购信息

以下页中包括机械封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5053CAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJCA
DRV5053CAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJCA
DRV5053CAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJCA
DRV5053CAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJCA
DRV5053CAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJCA
DRV5053CAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJCA
DRV5053CAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJCA
DRV5053CAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKCA
DRV5053CAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKCA
DRV5053CAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	+AKCA
DRV5053CAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKCA
DRV5053CAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKCA
DRV5053CAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKCA
DRV5053CAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKCA
DRV5053EAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJEA
DRV5053EAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJEA
DRV5053EAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJEA
DRV5053EAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJEA
DRV5053EAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJEA
DRV5053EAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJEA
DRV5053EAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJEA
DRV5053EAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AKEA
DRV5053EAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AKEA
DRV5053EAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AKEA
DRV5053EAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AKEA
DRV5053EAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AKEA
DRV5053EAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKEA
DRV5053EAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKEA
DRV5053OAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJOA

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5053OAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJOA
DRV5053OAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJOA
DRV5053OAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJOA
DRV5053OAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJOA
DRV5053OAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJOA
DRV5053OAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJOA
DRV5053OAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKOA
DRV5053OAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKOA
DRV5053OAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	+AKOA
DRV5053OAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKOA
DRV5053OAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKOA
DRV5053OAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKOA
DRV5053OAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKOA
DRV5053PAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJPA
DRV5053PAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJPA
DRV5053PAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJPA
DRV5053PAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJPA
DRV5053PAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJPA
DRV5053PAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJPA
DRV5053PAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJPA
DRV5053PAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKPA
DRV5053PAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKPA
DRV5053PAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	+AKPA
DRV5053PAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKPA
DRV5053PAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKPA
DRV5053PAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKPA
DRV5053PAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKPA
DRV5053RAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJRA
DRV5053RAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJRA
DRV5053RAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJRA
DRV5053RAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJRA

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
DRV5053RAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJRA
DRV5053RAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJRA
DRV5053RAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJRA
DRV5053RAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKRA
DRV5053RAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKRA
DRV5053RAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	+AKRA
DRV5053RAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKRA
DRV5053RAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKRA
DRV5053RAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-	+AKRA
DRV5053RAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AKRA
DRV5053VAEDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJVA
DRV5053VAEDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 150	+AJVA
DRV5053VAEDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 150	+AJVA
DRV5053VAELPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJVA
DRV5053VAELPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 150	+AJVA
DRV5053VAELPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJVA
DRV5053VAELPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 150	+AJVA
DRV5053VAQDBZRQ1	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKVA
DRV5053VAQDBZRQ1.A	Active	Production	SOT-23 (DBZ) 3	3000 LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 125	+AKVA
DRV5053VAQDBZTQ1	Obsolete	Production	SOT-23 (DBZ) 3	-	-	Call TI	Call TI	-40 to 125	+AKVA
DRV5053VAQLPGMQ1	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKVA
DRV5053VAQLPGMQ1.A	Active	Production	TO-92 (LPG) 3	3000 AMMO	Yes	SN	N/A for Pkg Type	-40 to 125	+AKVA
DRV5053VAQLPGQ1	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKVA
DRV5053VAQLPGQ1.A	Active	Production	TO-92 (LPG) 3	1000 BULK	Yes	SN	N/A for Pkg Type	-40 to 125	+AKVA

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF DRV5053-Q1 :

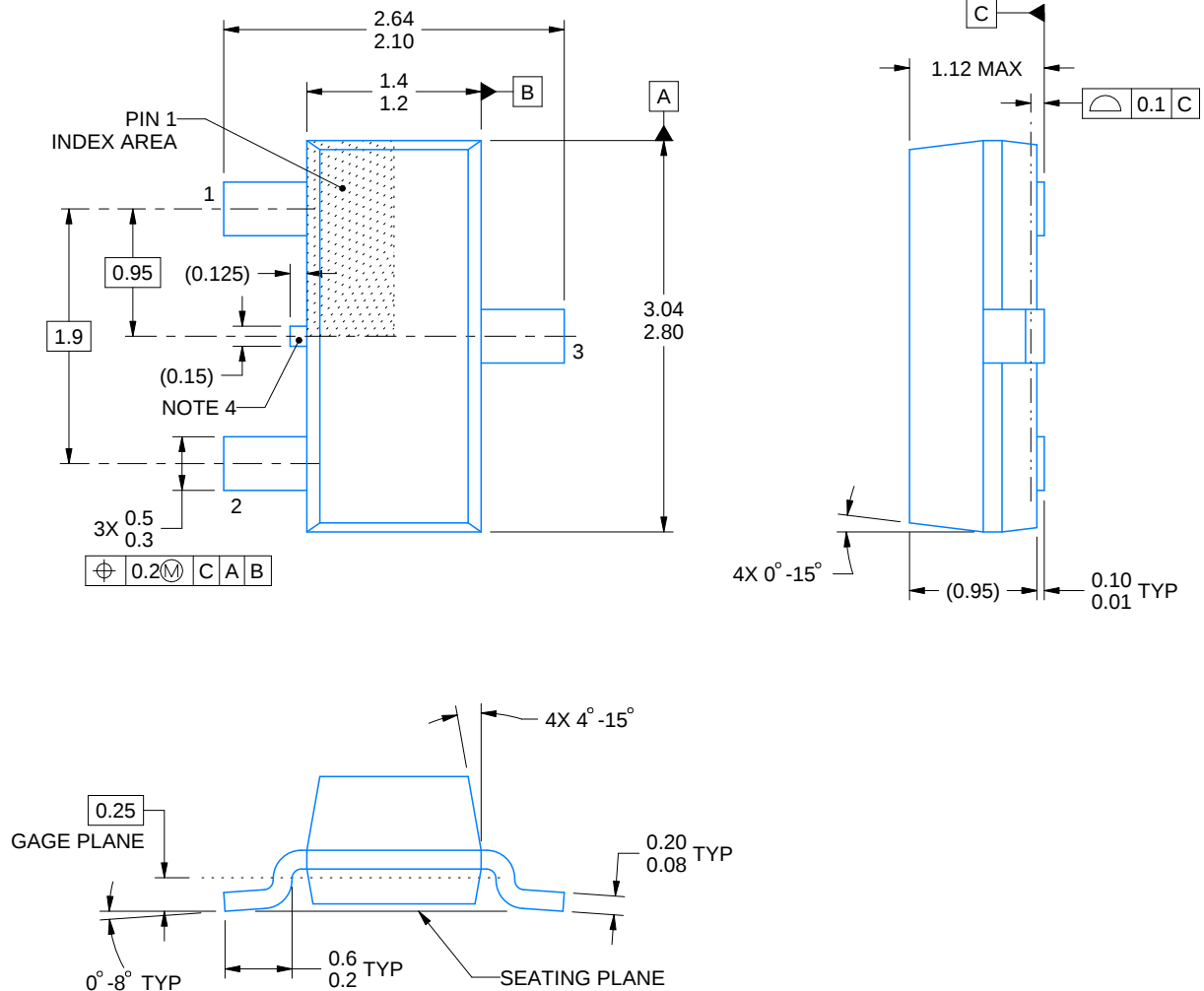
- Catalog : [DRV5053](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

DBZ0003A**PACKAGE OUTLINE****SOT-23 - 1.12 mm max height**

SMALL OUTLINE TRANSISTOR



4214838/F 08/2024

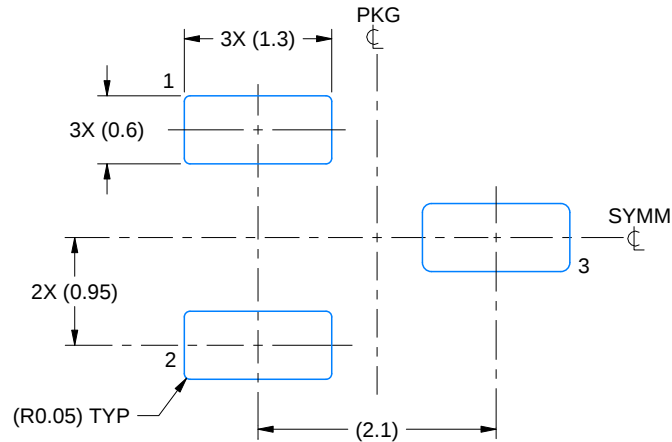
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.
4. Support pin may differ or may not be present.
5. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

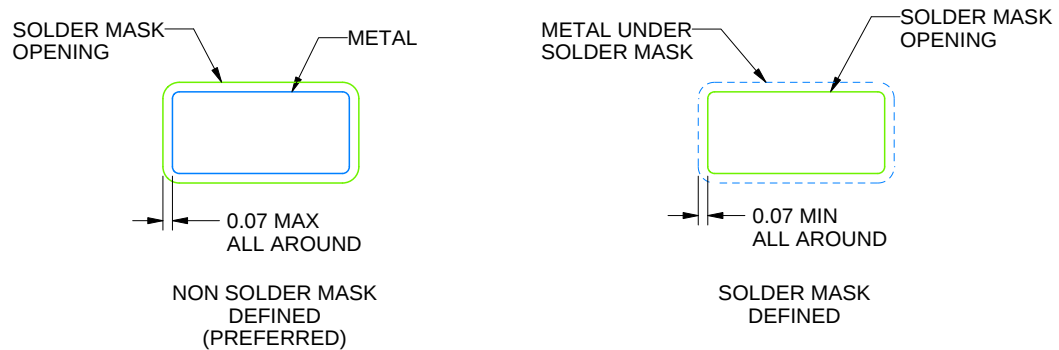
DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
SCALE:15X



SOLDER MASK DETAILS

4214838/F 08/2024

NOTES: (continued)

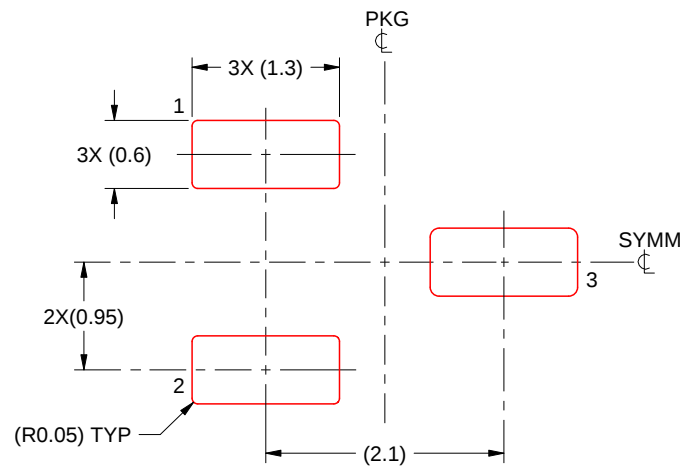
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBZ0003A

SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

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NOTES: (continued)

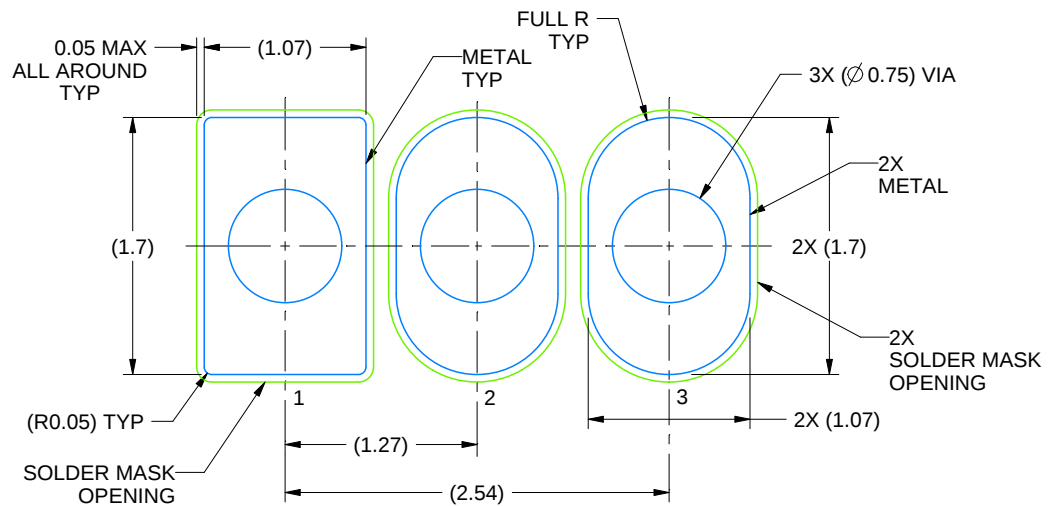
7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

EXAMPLE BOARD LAYOUT

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



LAND PATTERN EXAMPLE
NON-SOLDER MASK DEFINED
SCALE:20X

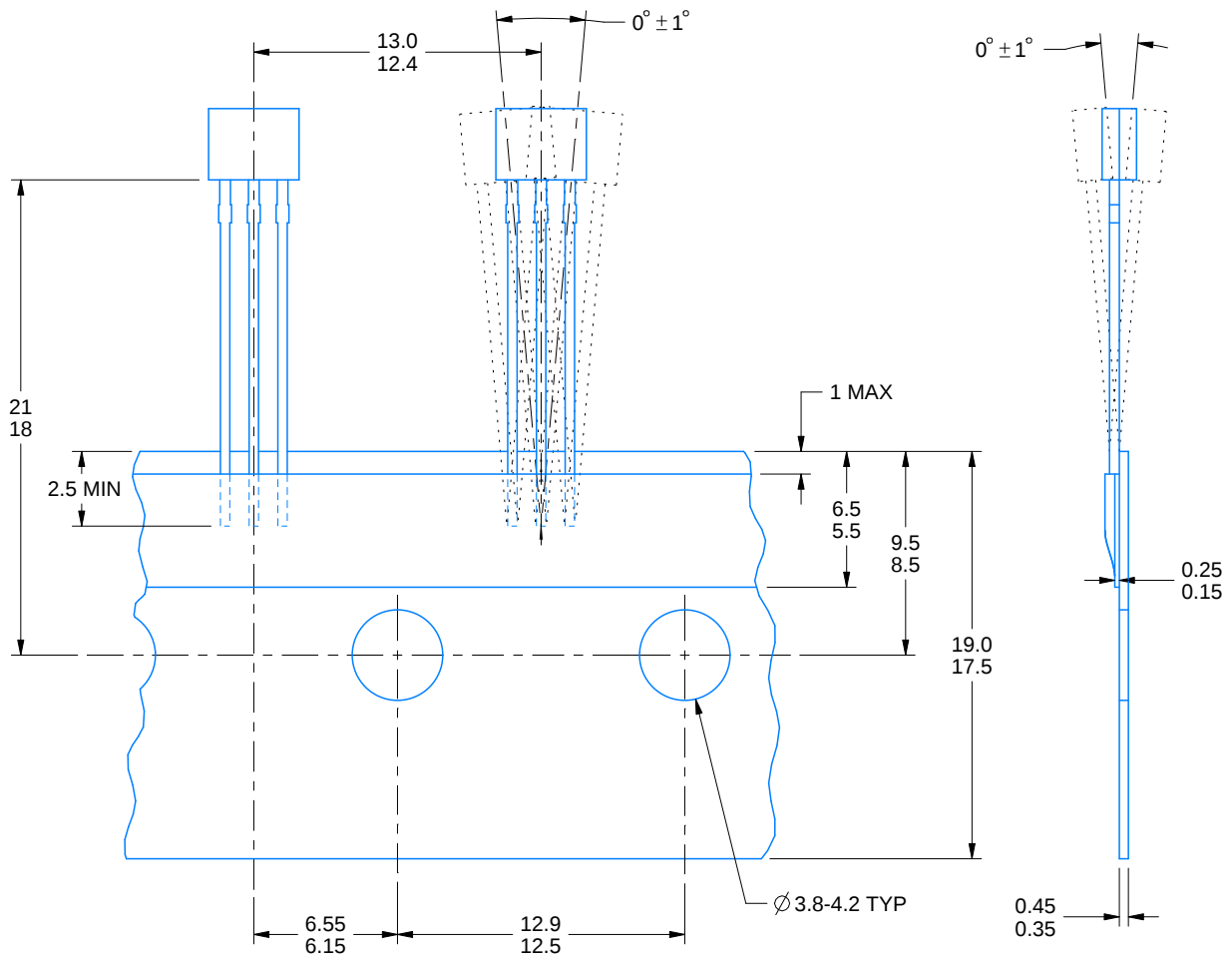
4221343/C 01/2018

TAPE SPECIFICATIONS

LPG0003A

TO-92 - 5.05 mm max height

TRANSISTOR OUTLINE



4221343/C 01/2018

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